NCE N-Channel Enhancement Mode Power MOSFET

DESCRIPTION

The NCE5549 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

GENERAL FEATURES

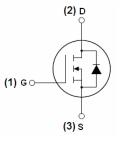
- V_{DS} =55V, I_D =49A $R_{DS(ON)} < 15m\Omega$ @ V_{GS} =10V (Typ:9m Ω)
- High density cell design for ultra low Rdson
- Fully characterized Avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

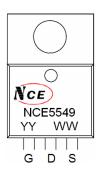
- Power switching application
- Hard Switched and High Frequency Circuits
- Uninterruptible Power Supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin Assignment



TO-220 top view

Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE5549	NCE5549	TO-220	-	-	-

Absolute Maximum Ratings (TA=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	55	V
Gate-Source Voltage	V _G S	±20	V
Drain Current-Continuous	I _D	49	Α
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	35	Α
Pulsed Drain Current	I _{DM}	195	Α
Maximum Power Dissipation	P _D	120	W
Derating factor		0.8	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	450	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$



NCE5549

Thermal Characteristic

Thermal Resistance, Junction-to-Case(Note 2)	$R_{ heta JC}$	1.25	°C/W	
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Electrical Characteristics (TA=25°Cunless otherwise noted)

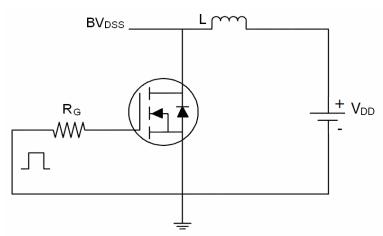
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	•		•	•		
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	55	65	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =55V,V _{GS} =0V		-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	2	3	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =30A	-	9	15	mΩ
Forward Transconductance	g FS	V _{DS} =25V,I _D =30A	20	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss})/ O5)/// O)/	-	2350	-	PF
Output Capacitance	C _{oss}	V_{DS} =25V, V_{GS} =0V,	-	237	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	205	-	PF
Switching Characteristics (Note 4)	•		•	•		
Turn-on Delay Time	t _{d(on)}		-	12	-	nS
Turn-on Rise Time	t _r	V_{DD} =30V, I_{D} =2A, R_{L} =15 Ω	-	10	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =2.5 Ω	-	45	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg	V 20VI 20A	-	50	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =30V,I _D =30A,	-	12	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	16	-	nC
Drain-Source Diode Characteristics				JI.		
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =30A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	49	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =75A	-	28		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs(Note3) - 49		nC		
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

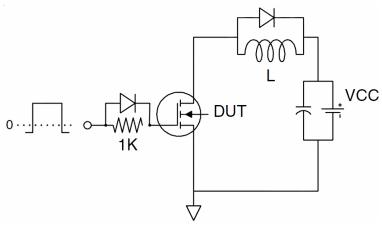
- **1.** Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}\text{C}$,VDD=30V,VG=10V,L=0.5mH,Rg=25 Ω

Test circuit

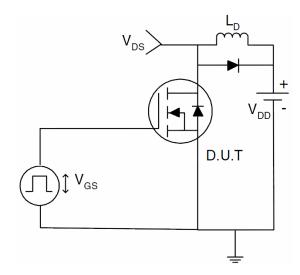
1) E_{AS} test Circuits



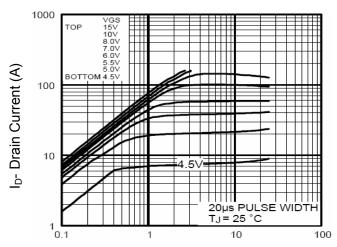
2) Gate charge test Circuit:



3) Switch Time Test Circuit:



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (Curves)



Vds Drain-Source Voltage (V)

Figure 1 Output Characteristics

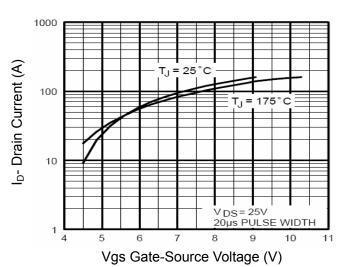


Figure 2 Transfer Characteristics

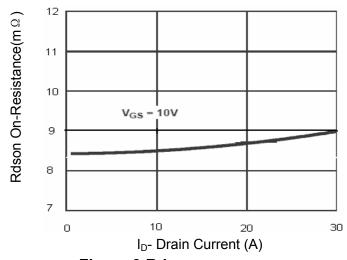


Figure 3 Rdson- Drain Current

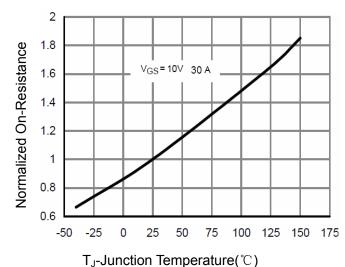


Figure 4 Rdson-JunctionTemperature

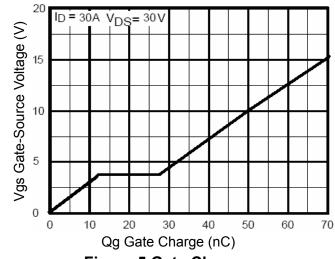


Figure 5 Gate Charge

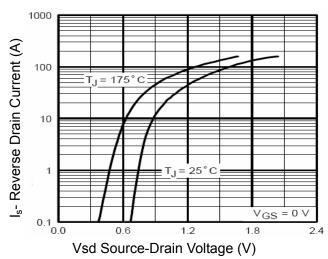


Figure 6 Source- Drain Diode Forward

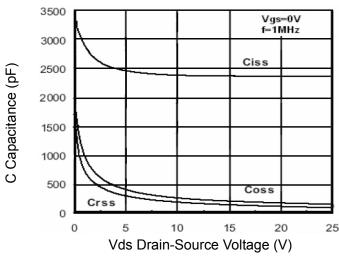


Figure 7 Capacitance vs Vds

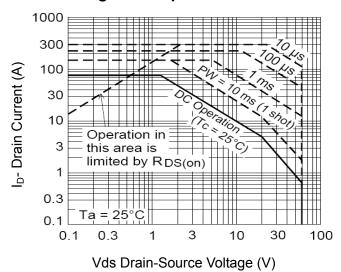


Figure 8 Safe Operation Area

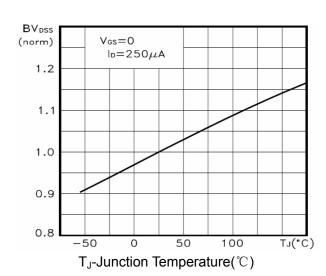


Figure 9 BV_{DSS} vs Junction Temperature

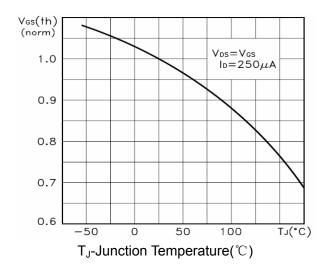


Figure 10 V_{GS(th)} vs Junction Temperature

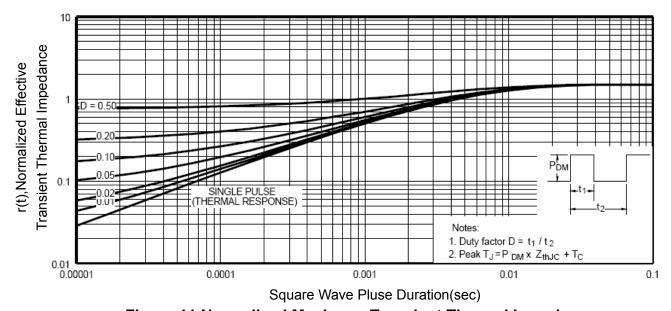
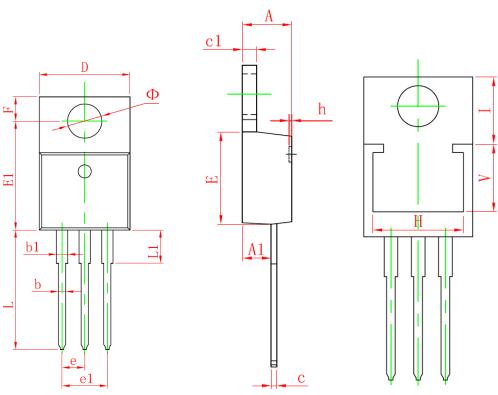


Figure 11 Normalized Maximum Transient Thermal Impedance

TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
A	4.470	4.670	0.176	0.184		
A1	2.520	2.820	0.099	0.111		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
c	0.330	0.650	0.013	0.026		
c1	1.200	1.400	0.047	0.055		
D	10.010	10.350	0.394	0.407		
E	8.500	8.900	0.335	0.350		
E1	12.060	12.460	0.475	0.491		
e	2.540	2.540 (TYP.)		0.100 (TYP.)		
e1	4.980	5.180	0.196	0.204		
F	2.590	2.890	0.102	0.114		
Н	8.44	140 REF. 0.332 REF.		REF.		
h	0.000	0.300	0.000	0.012		
L	13.400	13.800	0.528	0.543		
L1	3.560	3.960	0.140	0.156		
V	6.360 REF.		0.250 REF.			
I	6.300 REF.		0.248 REF.			
Ф	3.735	3.935	0.147	0.155		

Pb Free Product

NCE5549

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